#### POWER OF ATTORNEY BY ASSIGNEE OF ENTIRE INTEREST

#### Revocation of Power of Attorney with New Power of Attorney

NANYA TECHNOLOGY CORP., as assignee of record of the entire right, title and interest in each of the patent application(s) or patent(s) listed in the table of Attachment A, hereby revoke all powers of attorney previously given in each of the listed patent application(s) or patent(s) and appoint all practitioners associated with the Customer Number:

27765

as the attorney(s) or agent(s) to represent the undersigned before the United States Patent and Trademark Office (USPTO) in connection with any and all of the listed patent application(s) and patent(s).

Please recognize or change the correspondence address for the above-identified application to the address associated with the above-mentioned Customer Number.

#### Statement under 37 CFR 3.73(b)

I hereby state that, as required by 37 CFR 3.73(b)(1)(i), the documentary evidence of the chain of title from the original owner to the assignee was, or concurrently is being, submitted for recordation pursuant to 37 CFR 3.11. The chain of title is indicated in the table of Attachment A.

Pursuant to 37 CFR 3.71, I hereby state the prosecution of the listed application(s) or reexamination of the listed patent(s) is to be conducted to the exclusion of both the inventor(s) and previous assignee(s).

The undersigned is authorized to act on behalf of the assignee.

Signature

Name

Title

Jih Lien

President

Date Sept. 8, 2009

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# Attachment A

					Chain of Title	
Appl. No.	Filing Date	Title	, o	from	ß	Reel/Frame No.
			-	LANE, RICHARD	JINI ADO IOINFIDEL INOGOJIV	010300/0415
				THAKUR, RANDHIR PS		0.5010
09/135,474	09/135,474 1998/08/17	PROCESS FOR MAKING AN ISOLATION STRUCTURE	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			,	LANE, RICHARD		
			-1	THAKUR, RANDHIR PS	MICKON IECHNOLOGY, INC.	010390/0415
09/911,580	09/911,580 2001/07/24	ISOLATION STRUCTURE AND PROCESS THEREFOR	74	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
09/291,127	09/291,127 1999/04/13	ELECTRODE AND CAPACITOR STRUCTURE FOR A	H	AGARWAL, VISHNU K.	MICRON TECHNOLOGY, INC.	009897/0668

	SEMICONDUCTOR DEVICE AND ASSOCIATED METHODS OF MANUFACTURE	2 Micron Technology, Inc.	7, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		1 AGARWAL, VISHNU K.	NU K.	MICRON TECHNOLOGY, INC.	011193/0819
09/654,997/2000/08/31	CAPACITOR AND ELECTRODE STRUCTURES FOR A SEMICONDUCTOR DEVICE	2 Micron Technology, Inc.	у, Іпс.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
1		1 FARRAR, PAUL A	.A.	MICRON TECHNOLOGY, INC.	009376/0238
09/128,859 1998/08/04	COPPER METALLURGY IN INTEGRATED CIRCUITS	2 Micron Technology, Inc.	y, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		1 FARRAR, PAUL A.	.A.	MICRON TECHNOLOGY, INC.	009376/0238
09/946,055 2001/09/04	COPPER METALLURGY IN INTEGRATED CIRCUITS	2 Micron Technology, Inc.	y, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
09/033,064 1998/02/28	METHOD OF FORMING HIGH-K OXYGEN-CONTAINING DIELECTRIC LAYERS INCLUDING MANUFACTURE OF CAPACITORS AND DRAM CELLS	AL-SHAREEF, HUSAM N. DEBOER, SCOTT JEFFREY THAKUR, RANDHIR P. S.	AM N. FFREY IR P. S.	MICRON TECHNOLOGY, INC.	009013/0121

		7	THAKUR, RANDHIR P.S.	MICRON TECHNOLOGY, INC.	009261/0355
		က	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			FORBES, LEONARD NOBLE, WENDELL P.	MICRON TECHNOLOGY, INC.	010202/0223
	MOSFET TECHNOLOGY FOR PROGRAMMABLE		CLOUD, EUGENE H.		
09/383,804 1999/08/26	ADDRESS DECODE AND CORRECTION	7	Містоп Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			FORBES, LEONARD		
		Н	NOBLE, WENDELL P.	MICRON TECHNOLOGY, INC.	010202/0223
00,000,000	PROGRAMMABLE MOSFET TECHNOLOGY AND		CLOUD, EUGENE H.		
09/924,659/2001/08/08	FROGRAMMABLE ADDRESS DECODE AND CORRECTION	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

207 606010	010202/0222	attached and concurrently submitted for recordation	010219/0912	attached and concurrently submitted for recordation	008679/0825	attached and concurrently submitted for recordation
ONI AGO IOMHOBLI NOBOLIV	MICROIN IECTHAOLOGI, HAC	NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.
FORBES, LEONARD	CLOUD, EUGENE H.	Micron Technology, Inc.	PING, ER-XUAN HUANG, YING	Micron Technology, Inc.	CASPER, STEPHEN L. PINNEY, DAVID KEETH, BRENT	Micron Technology, Inc.
	<b>-</b>	7	F-4	7	Т	- 7
	PROGRAMMABLE MEMORY CELL USING CHARGE	TRAPPING IN A GATE OXIDE		09/389,294 1999/09/02 REDUCTION OF SHORTS AMONG ELECTRICAL CELLS FORMED ON A SEMICONDUCTOR SUBSTRATE	CIRCUIT AND METHOD FOR MEMORY DEVICE WITH	
		94/01/22		99/09/02		97/08/14
		10/763,136 2004/01/22		09/389,294 199		08/911,6671997/08/14

008679/0825	attached and concurrently submitted for recordation	008679/0825	attached and concurrently submitted for recordation	008679/0825	attached and concurrently submitted for recordation
MICRON TECHNOLOGY, INC.	NANYA TECHINOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.
CASPER, STEPHEN L. PINNEY, DAVID KEETH, BRENT	Micron Technology, Inc.	CASPER, STEPHEN L. PINNEY, DAVID KEETH, BRENT	Micron Technology, Inc.	CASPER, STEPHEN L. PINNEY, DAVID KEETH, BRENT	Micron Technology, Inc.
H-1	74		7	1 1	7
CIRCUIT AND METHOD FOR MEMORY DEVICE WITH		CIRCUIT AND METHOD FOR MEMORY DEVICE WITH		Circuit and method for memory device with defect current	
	99/02/26		99/01/26		00/03/20
	09/261,607 1999/02/26		09/237,362 1999/01/26		09/528,400 2000/03/20

			H	SHIRLEY, BRIAN M.	MICRON TECHNOLOGY, INC.	009012/0671
09/026,603 1998/02/20	998/02/20	TWISTED GLOBAL COLUMN DECODER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			F-1	SHIRLEY, BRIAN M.	MICRON TECHNOLOGY, INC.	009012/0671
09/362,076 1999/07/27	.999/07/27	TWISTED GLOBAL COLUMN DECODER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			H-1	SHIRLEY, BRIAN M.	MICRON TECHNOLOGY, INC.	009012/0671
09/583,439 2000/05/31	2000/05/31	TWISTED GLOBAL COLUMN DECODER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			г	MORGAN, DONALD M.	MICRON TECHNOLOGY, INC.	011385/0718
09/651,639	09/651,639 2000/08/30	MID ARRAY ISOLATE CIRCUIT LAYOUT	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
10/229,555	10/229,555 2002/08/28	Mid-array isolate circuit layout and method		MORGAN, DONALD M.	MICRON TECHNOLOGY, INC.	011385/0718

attached and concurrently submitted for recordation	011062/0306		attached and concurrently submitted for recordation		011042/0154		attached and concurrently submitted for recordation
NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.		NANYA TECHNOLOGY CORP.		MICRON TECHNOLOGY, INC.		NANYA TECHNOLOGY CORP.
Micron Technology, Inc.	MANNING, TROY A. MARTIN, CHRIS G. BATRA, SHUBNEESH	MORGAN, DONALD M.	Micron Technology, Inc.	MERRITT, TODD A.	INGALLS, CHARLES L.	RAAD, GEORGE B.	Micron Technology, Inc.
7	F	_	7		-	-	2
		Antifuse method to repair columns in a prefetched output					Equilibration/pre-charge circuit for a memory device
		2000/08/25					2000/08/25
		09/648,921 2000/08/25					09/645,577 2000/08/25

			BEFFA, RAY J.		
			WALLER, WILLIAM K.		
		Н	NEVILL, LELAND R.	MICRON TECHNOLOGY, INC.	008537/0289
			FARNWORTH, WARREN M.		
08/838,010 1997/04/22	SELF-TEST OF A MEMORY DEVICE		CLOUD, EUGENE H.		
			Micron Technology Inc	NANYA TECHNOLOGY CORP.	attached and concurrently
		٧	ישרוטון זבניתוסיס אל ישני.		submitted for recordation
			KEETH, BRENT		
			MANNING, TROY A.		
			MARTIN, CHRIS G.		
			PIERCE, KIM M.		
10/886,195 1997/07/01	METHOD AND APPARATUS FOR MEMORY ARRAY		FISTER, WALLACE E.	MICRON TECHNOLOGY, INC.	009373/0058
			RYAN, KEVIN J.		
			LEE, TERRY R.		
			PEARSON, MIKE		
			VOSHELL, THOMAS W.		

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F-1
09/352.3521999/07/13 TEST AND OBSERVE MODE FOR EMBEDDED MEMORY
м
1
ANTIREFLECTIVE COATING LAYER  2

				HU, YONGJUN	Micron Technology, Inc.	008777/0373
09/631,264 2000/08/02	0/08/05	PHOTOLITHOGRAPHY METHOD USING AN ANTIREFLECTIVE COATING	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			П	HU, YONGJUN	Micron Technology, Inc.	008777/0373
09/476,558 2000/01/03	0/01/03	ANTIREFLECTIVE COATING LAYER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			<u></u>	JOO, YANGSUNG	MICRON TECHNOLOGY, INC.	013267/0389
10/233,997 2002/08/29	12/08/29	DRIVING A DRAM SENSE AMPLIFIER HAVING LOW THRESHOLD VOLTAGE PMOS TRANSISTORS	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			Н.	JOO, YANGSUNG	MICRON TECHNOLOGY, INC.	013267/0389
10/783,976 2004/02/20	14/02/20	DRIVING A DRAM SENSE AMPLIFIER HAVING LOW THRESHOLD VOLTAGE PMOS TRANSISTORS	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
10/696,971 2003/10/30	10/30	Data compression read mode for memory testing		NASO, GIOVANNI	MICRON TECHNOLOGY, INC.	014659/0206

attached and concurrently submitted for recordation	C. 011693/0081	attached and concurrently submitted for recordation	C. 013251/0264	attached and concurrently submitted for recordation	C. 013251/0264	attached and concurrently submitted for recordation
NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.
Micron Technology, Inc.	MERRITT, TODD A. THOMPSON, J. WAYNE	Micron Technology, Inc.	MARR, KENNETH W. PORTER, JOHN D.	Micron Technology, Inc.	MARR, KENNETH W. PORTER, JOHN D.	Micron Technology, Inc.
2		7	н	7	1	71
		Metal wiring pattern for memory devices		10/230,928 2002/08/29 GATE DIELECTRIC ANTIFUSE CIRCUIT TO PROTECT A HIGH-VOLTAGE TRANSISTOR		GATE DIELECTRIC ANTIFUSE CIRCUIT TO PROTECT A HIGH-VOLTAGE TRANSISTOR
		09/805,913 2001/03/15		2002/08/29		10/931,366 2004/08/31
		09/805,913		10/230,928		10/931,366

				KIRSCH, HOWARD		
			Н	KIM, TAE HYOUNG	MICRON TECHNOLOGY, INC.	013255/0858
				INGALLS, CHARLES L.		
10/231,389 2002/08/29	02/08/29	WORD LINE DRIVER FOR NEGALIVE VOLLAGE	74	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
				KIM, TAE HYOUNG		
		SYSTEM AND METHOD FOR NEGATIVE WORD LINE	Н	VO, HUY BLODGETT, GREG	MICRON TECHNOLOGY, INC.	013543/0899
10/232,953 2002/08/29	02/08/29		71	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			-	KIM, TAE HYOUNG VO, HUY	MICRON TECHNOLOGY, INC.	013543/0899
10/860,881 2004/06/03	04/06/03	SYSTEM AND METHOD FOR NEGATIVE WORD LINE DRIVER CIRCUIT	7	BLODGE 11, GREG	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

			AHN. KIE Y.		
		<b>~</b>	FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
08/950,319 1997/10/14 POROUS SILICON OXYCARBIDE INTEGRATED CIRCUIT INSULATOR	VTED .	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		1	AHN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
09/517,029 2000/03/02 Porous silicon oxycarbide integrated circuit insulator	sulator	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		1	AHN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
09/909,532 2001/07/20 POROUS SILICON OXYCARBIDE INTEGRATED CIRCUIT INSULATOR	 ATED	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		1	AHN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
10/083,051 2002/02/26 POROUS SILICON OXYCARBIDE INTEGRATED CIRCUIT INSULATOR	ATED	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

006665/0347	attached	attached and concurrently submitted for recordation	007460/0835	009187/0739	attached and concurrently submitted for recordation	007811/0575	008235/0516
MICRON SEMICONDUCTOR, INC.	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	MICRON SEMICONDUCTOR, INC.	MICRON TECHNOLOGY INC.	NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	MICRON TECHNOLOGY, INC., A DELAWARE CORP
THAKUR, RANDHIR P.S. GONZALEZ, FERNANDO	MICRON SEMICONDUCTOR, INC.	Micron Technology, Inc.	THAKUR, RANDHIR P.S.	MICRON SEMICONDUCTOR, INC.	Micron Technology, Inc.	THAKUR, RANDHIR P.S. GONZALEZ, FERNANDO	THAKUR, RANDHIR P.S. GONZALEZ, FERNANDO
F1		8	7 7		6	1	7
METHOD FOR OPTIMIZING THERMAL BUDGETS IN FABRICATING SEMICONDUCTORS			METHOD FOR OPTIMIZING THERMAL BUDGETS IN		METHOD FOR OPTIMIZING THERMAL BUDGETS IN FABRICATING SEMICONDUCTORS		
90/80/86		995/04/25			995/11/15		
08/102,908 1993/08/06		08/427,941 1995/04/25			08/559,511 1995/11/15		

		m	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			KIRSCH, HOWARD C.	MICRON TECHNOLOGY, INC.	013256/0297
10/231,626 2002/08	METHOD AND CIRCUIT FOR REDUCING DRAM 10/231,626 2002/08/29 REFRESH POWER BY REDUCING ACCESS TRANSISTOR SUB THRESHOLD LEAKAGE	6	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		₩.	KIRSCH, HOWARD C.	MICRON TECHNOLOGY, INC.	013256/0297
11/040,959/2005/01	METHOD AND CIRCUIT FOR REDUCING DRAM 11/040,959 2005/01/19 REFRESH POWER BY REDUCING ACCESS TRANSISTOR SUB THRESHOLD LEAKAGE	7	Micron Technology, Inc.	NANYA TECHINOLOGY CORP.	attached and concurrently submitted for recordation
	INOITA STIATION SOMEWORK BY AND VALVE	₽-1	JOO, YANGSUNG PINNEY, DAVID L. BROWN, JASON	MICRON TECHNOLOGY, INC.	015741/0152
70, 726, 37, 700, 40, 70, 70, 70, 70, 70, 70, 70, 70, 70, 7		2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
08/666,617 1996/06/18	/18 Voltage generator for antifuse programming	<del>,</del>	SHER, JOSEPH C.	MICRON TECHNOLOGY, INC.	008063/0562

attached and concurrently submitted for recordation	. 011067/0527	attached and concurrently submitted for recordation
NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	NANYA TECHNOLOGY CORP.
Micron Technology, Inc.	FORBES, LEONARD	Micron Technology, Inc.
74	H	7
		Clock-delayed pseudo-nmos domino logic
		09/651,630 2000/08/30
		09/651,630

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#### ASSIGNMENT

WHEREAS, Micron Technology, Inc., a corporation organized and existing under the laws of Delaware ("ASSIGNOR"), owns certain patent applications and/or registrations, as set forth in <u>Attachment 1</u> attached hereto and incorporated herein by this reference ("PATENTS"); and

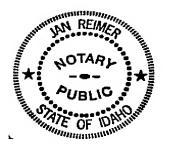
WHEREAS, Nanya Technology Corporation (南亞科技股份有限公司), a company incorporated under the laws of the Republic of China ("ASSIGNEE"), desires to acquire all of the right, title and interest of ASSIGNOR in, to and under the PATENTS;

WHEREAS, ASSIGNOR and ASSIGNEE have entered into a certain Patent Assignment Agreement, dated June 6, 2008 assigning, all of ASSIGNOR's right, title and interest in and to the PATENTS from ASSIGNOR to ASSIGNEE upon the terms and subject to the conditions set for the in the Patent Assignment Agreement;

Now, Therefore, in consideration of the sum of One Dollar (\$1.00) and other good and valuable consideration from ASSIGNEE to ASSIGNOR, the receipt and sufficiency of which hereby is acknowledged, ASSIGNOR does hereby sell, assign, transfer and convey unto ASSIGNEE all of ASSIGNOR's right, title and interest in and to the PATENTS, including all rights to causes of action and remedies related thereto (including, the right to sue for past, present or future infringement related to the foregoing) upon the terms and subject to the conditions set forth in the Patent Assignment Agreement;

y commission expires on

WITNESS my hand and official seal.



### Micron NTC '

# ATTACHMENT 1 PATENTS

SERIAL NUMBER OR	FILING DATE
REGISTRATION NUMBER	
6265282	8/17/1998
6414364	7/24/2001
6218256	4/13/1999
6346746	8/31/2000
6284656	8/4/1998
6614099	9/4/2001
6162744	2/28/1998
6521958	8/26/1999
6700821	8/8/2001
6909635	1/22/2004
6399983	9/2/1999
5896334	8/14/1997
6041003	2/26/1999
6118728	1/26/1999
6154401	3/20/2000
5949698	2/20/1998
6111774	7/27/1999
6480408	5/31/2000
6574128	8/30/2000
6714434	8/28/2002
6301164	8/25/2000
6333882	8/25/2000
5910921	4/22/1997
5935263	7/1/1997
6154851	8/5/1997
6535999	7/13/1999
6614085	10/31/2001
6627389	8/2/2000
6753584	1/3/2000
6728151	8/29/2002
7002863	2/20/2004
7254756	10/30/2003
6664634	3/15/2001
6936909	8/29/2002
7101738	8/31/2004
6754131	8/29/2002
6809986	8/29/2002
7203124	6/3/2004
6350704	10/14/1997
6313518	3/2/2000

## Micron NTC

6803326	7/20/2001
6710428	2/26/2002
5409858	8/6/1993
5474955	4/25/1995
5646075	11/15/1995
6888769	8/29/2002
7023751	1/19/2005
7038958	8/26/2004
5793224	6/18/1996
6373290	8/30/2000